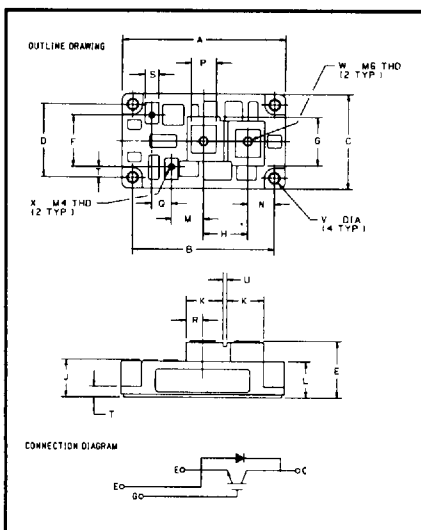


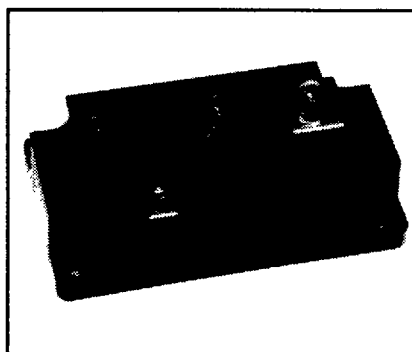
Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272  
 Powerex, Europe, S.A. 428 Avenue G. Durand, BP107, 72003 Le Mans, France (43) 41.14.14

POWEREX INC

### Single IGBTMOD™ E-Series Module 300 Amperes/600 Volts



**CM300HA-12E**  
 Outline Drawing



**CM300HA-12E**  
 Single IGBTMOD™ E-Series Module  
 300 Amperes/600 Volts

#### Description:

Powerex IGBTMOD™ Modules are designed for use in switching applications. Each module consists of one IGBT Transistor in a single configuration with a reverse-connected super-fast recovery free-wheel diode. All components and interconnects are isolated from the heat sinking baseplate, offering simplified system assembly and thermal management.

#### Features:

- Low Drive Power
- Low  $V_{CE(sat)}$
- Discrete Super-Fast Recovery (150ns) Free-Wheel Diode
- High Frequency Operation (15-20kHz)
- Isolated Baseplate for Easy Heat Sinking

#### Applications:

- AC Motor Control
- Motion/Servo Control
- UPS
- Welding Power Supplies
- Laser Power Supplies

#### Ordering Information:

Example: Select the complete part module number you desire from the table below

-i.e. CM300HA-12E is a 600V ( $V_{CES}$ ), 300 Ampere Single IGBTMOD™ Power Module.

Dimensions	Inches	Millimeters
A	4.21	107.0
B	3.661±0.01	93.0±0.25
C	2.44	62.0
D	1.89±0.01	48.0±0.25
E	1.42 Max.	36.0 Max.
F	1.34	34.0
G	1.18	30.0
H	1.14	29.0
J	0.98 Max.	25.0 Max.
K	0.94	24.0
L	0.93	23.5
M	0.83	21.0
N	0.69	17.5
P	0.63	16.0
Q	0.51	13.0
R	0.43	11.0
S	0.35	9.0
T	0.28	7.0
U	0.12	3.0
V	0.26 Dia.	Dia. 6.5
W	M6 Metric	M6
X	M4 Metric	M4

Type	Current Rating Amperes	$V_{CES}$ Volts (x 50)
CM	300	12

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**CM300HA-12E**  
 Single IGBTMOD™ E-Series Module  
 300 Amperes/600 Volts

### Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	CM300HA-12E	Units
Junction Temperature	$T_j$	-40 to 150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-40 to 125	$^\circ\text{C}$
Collector-Emitter Voltage (G-E SHORT)	$V_{CES}$	600	Volts
Gate-Emitter Voltage	$V_{GES}$	$\pm 20$	Volts
Collector Current	$I_C$	300	Amperes
Peak Collector Current	$I_{CM}$	600*	Amperes
Diode Forward Current	$I_{FM}$	300	Amperes
Diode Forward Surge Current	$I_{FM}$	600*	Amperes
Power Dissipation	$P_d$	1100	Watts
Max. Mounting Torque M6 Terminal Screws	-	26	in-lb
Max. Mounting Torque M6 Mounting Screws	-	26	in-lb
Module Weight (Typical)	-	400	Grams
V Isolation	$V_{RMS}$	2500	Volts

\* Pulse width and repetition rate should be such that device junction temperature does not exceed the device rating.

### Static Electrical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Cutoff Current	$I_{CES}$	$V_{CE} = V_{CES}; V_{GE} = 0V$	-	-	1.0	mA
Gate Leakage Current	$I_{GES}$	$V_{GE} = V_{GES}; V_{CE} = 0V$	-	-	0.5	$\mu\text{A}$
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$I_C = 30\text{mA}, V_{CE} = 10V$	3.5	5.0	6.5	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 300A, V_{GE} = 15V$	-	2.7	3.5**	Volts
		$I_C = 300A, V_{GE} = 15V, T_j = 150^\circ\text{C}$	-	2.7	-	Volts
Total Gate Charge	$Q_G$	$V_{CC} = 300V, I_C = 300A, V_{GS} = 15V$	-	1500	-	nC
Diode Forward Voltage	$V_{FM}$	$I_E = 300A, V_{GS} = 0V$	-	-	2.5	Volts

\*\* Pulse width and repetition rate should be such that device junction temperature rise is negligible

### Dynamic Electrical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

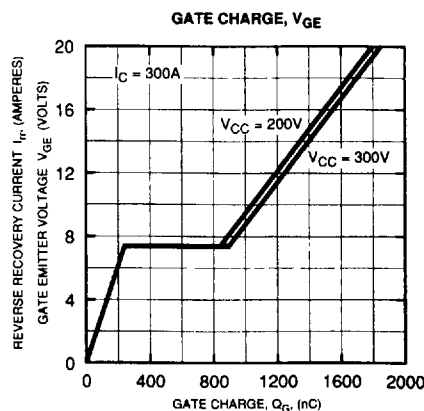
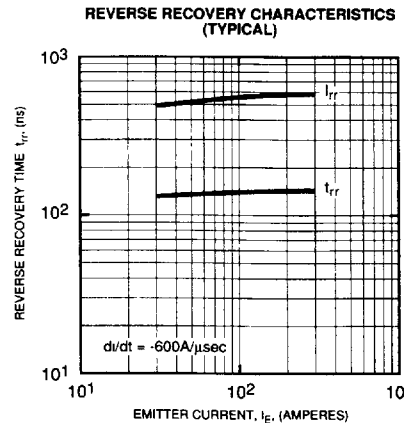
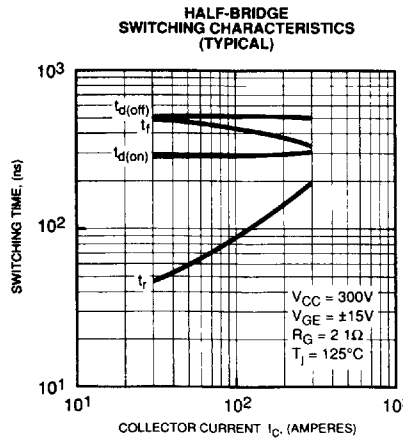
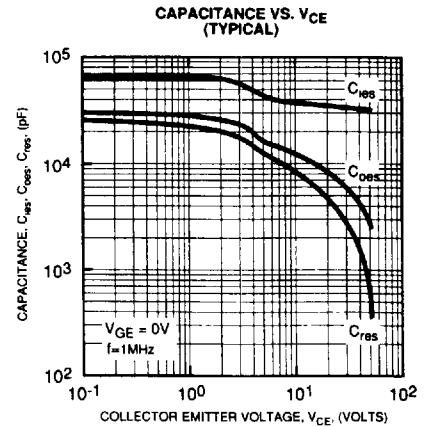
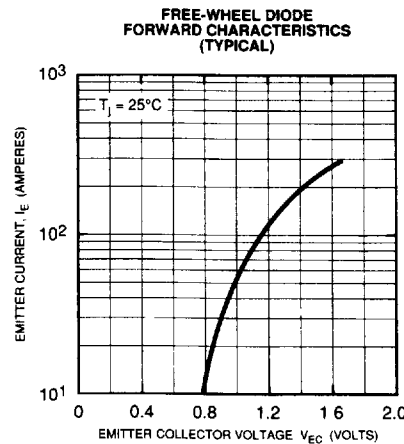
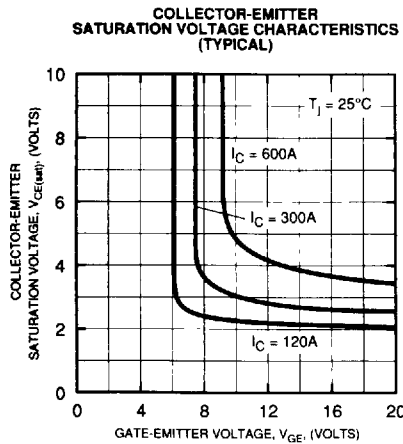
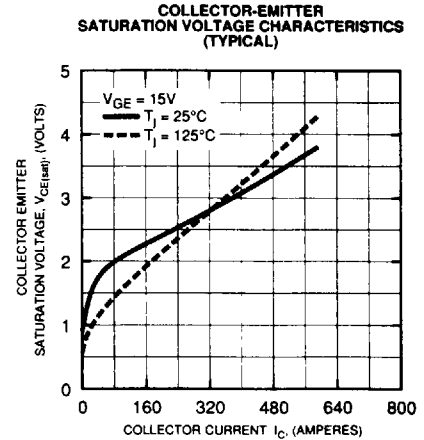
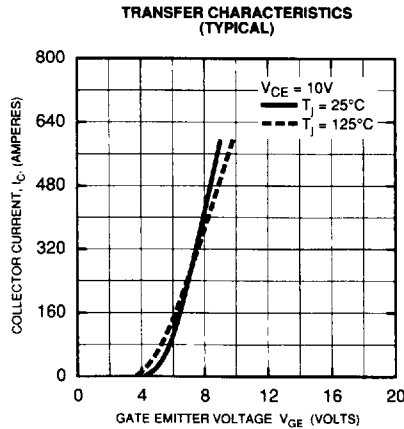
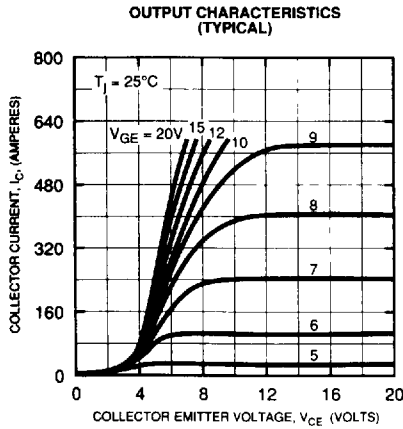
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units	
Input Capacitance	$C_{ies}$		-	-	60	nF	
Output Capacitance	$C_{oes}$	$V_{GE} = 0V, V_{CE} = 10V, f = 1\text{MHz}$	-	-	18	nF	
Reverse Transfer Capacitance	$C_{res}$		-	-	12	nF	
Resistive	Turn-on Delay Time	$V_{CC} = 300V, I_C = 300A,$ $V_{GE1} = V_{GE2} = 15V, R_G = 2.1\Omega$	-	-	400	ns	
Load	Rise Time		$t_r$	-	-	700	ns
Switch Times	Turn-off Delay Time		$t_d(off)$	-	-	800	ns
	Fall Time		$t_f$	-	-	350	ns
Diode Reverse Recovery Time	$t_{rr}$	$I_E = 300A, di_E/dt = -600A/\mu\text{s}$	-	-	200	ns	
Diode Reverse Recovery Charge	$Q_{rr}$	$I_E = 300A, di_E/dt = -600A/\mu\text{s}$	-	4.0	-	$\mu\text{C}$	

### Thermal and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction to Case	$R_{th(j-c)}$	Per IGBT	-	-	0.11	$^\circ\text{C/W}$
Thermal Resistance, Junction to Case	$R_{th(j-c)}$	Per Free Wheel Diode	-	-	0.24	$^\circ\text{C/W}$
Contact Thermal Resistance	$R_{th(c-f)}$	Per Module	-	-	0.04	$^\circ\text{C/W}$

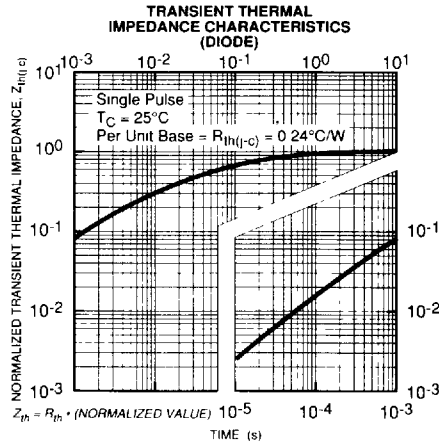
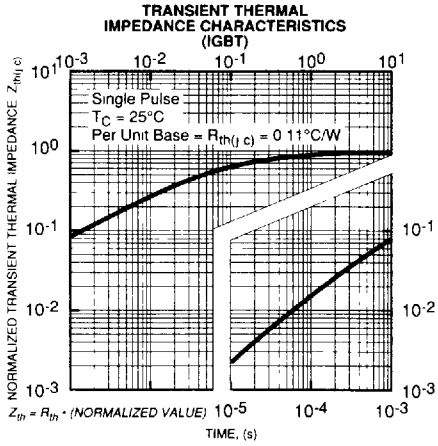
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**CM300HA-12E**  
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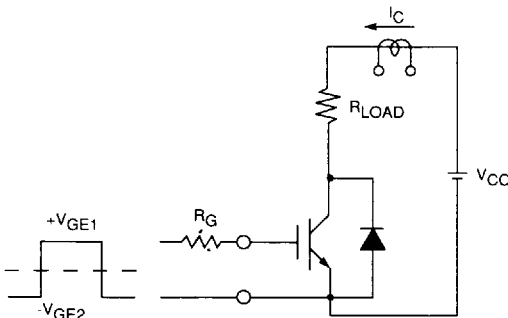


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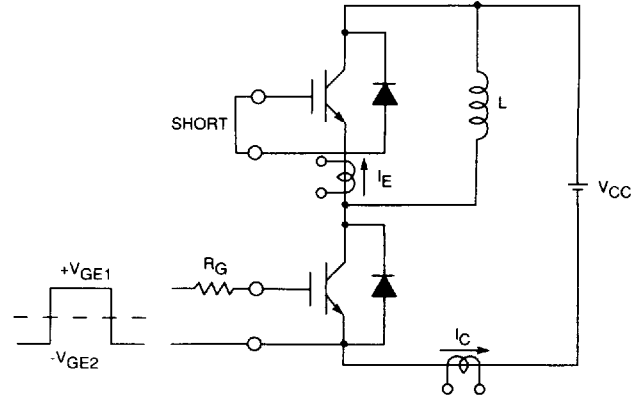
**CM300HA-12E**  
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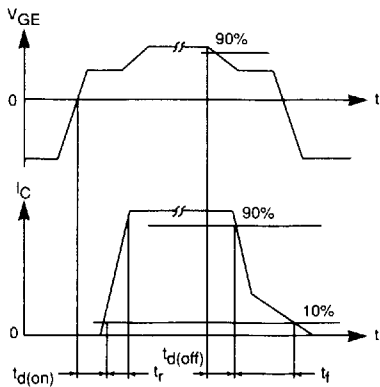
## SWITCHING TIME TEST CIRCUITS & WAVEFORMS



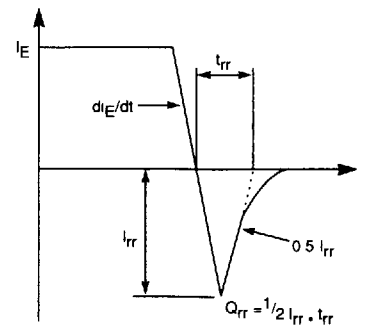
RESISTANCE LOAD SWITCHING TEST CIRCUIT



HALF-BRIDGE SWITCHING TEST CIRCUIT



SWITCHING TIME TEST WAVEFORMS



t<sub>rr</sub>, Q<sub>rr</sub> WAVEFORMS